

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	811	intrinsic near15 extrinsic near1 base	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 14:35
2	BRS	L2	700	emitter near2 pad	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 14:35
3	BRS	L3	1162	emitter near4 pad	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 14:36

	Type	L #	Hits	Search Text	DBs	Time Stamp
4	BRS	L4	0	(emitter near4 pad) near6 (distance near15 (intrinsic near base))	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 14:45
5	BRS	L6	0	5 and intrinsic	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 14:37
6	BRS	L5	9	(emitter near4 pad) near6 (distance near15 (base))	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 14:37

	Type	L #	Hits	Search Text	DBs	Time Stamp
7	BRS	L7	0	(emitter near4 pad) near6 (intrinsic near base)	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 14:45
8	BRS	L8	1210	(emitter) near6 (intrinsic near base)	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 14:59
9	BRS	L9	1342	(emitter) near9 (intrinsic near base)	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 14:46

	Type	L #	Hits	Search Text	DBs	Time Stamp
10	BRS	L10	124	8 and pad	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 14:47
11	BRS	L11	15	8 and pad near layer	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 14:47
12	BRS	L12	409	(emitter) near6 (intrinsic near base) near15 (transistor)	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 15:26

	Type	L #	Hits	Search Text	DBs	Time Stamp
13	BRS	L13	49	12 and pad\$1	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 15:00
14	BRS	L14	362	(emitter) near6 (intrinsic near base) near15 (extrinsic)	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 15:26
15	BRS	L15	350	(emitter) near6 (intrinsic near base) near15 (extrinsic near base)	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 15:33

	Type	L #	Hits	Search Text	DBs	Time Stamp
16	BRS	L16	83	(emitter) near6 (intrinsic near base) near15 (extrinsic near base) near5 (transistor)	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 15:59
17	BRS	L17	40	(emitter) near6 (intrinsic near base) near15 (extrinsic near base) near25 (oxide)	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 16:35
18	BRS	L18	0	(emitter) near6 (intrinsic near base) near15 (first near extrinsic near base) near25 (oxide)	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 16:35

	Type	L #	Hits	Search Text	DBs	Time Stamp
19	BRS	L19	0	(emitter) near6 (intrinsic near base) near15 (second near extrinsic near base) near25 (oxide)	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 16:36
20	BRS	L20	0	(emitter) near16 (intrinsic near base) near15 (second near extrinsic near base) near25 (oxide)	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 16:36
21	BRS	L21	1	(emitter) near16 (intrinsic near base) near15 (extrinsic near base) near25 (oxide) near35 (resistance)	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 16:41

	Type	L #	Hits	Search Text	DBs	Time Stamp
22	BRS	L22	0	(emitter) near16 (intrinsic near base) near15 (extrinsic near base) near25 (oxide) near35 (base near5 resistance)	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 16:42
23	BRS	L23	0	(emitter) near16 (intrinsic) near15 (extrinsic near base) near25 (oxide) near35 (base near5 resistance)	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 16:42
24	BRS	L24	0	(emitter) near16 (intrinsic) near15 (extrinsic) near25 (oxide) near35 (base near5 resistance)	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 16:42



	Type	L #	Hits	Search Text	DBs	Time Stamp
25	BRS	L25	35	(emitter) near16 (intrinsic) near15 (extrinsic) near25 (oxide) and (base near5 resistance)	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 16:44
26	BRS	L26	28	(emitter) near16 (intrinsic) near15 (extrinsic) same ((oxide) and (base near2 resistance))	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 16:44
27	BRS	L27	25	(emitter) near16 (intrinsic near base) near15 (extrinsic) same ((oxide) and (base near2 resistance))	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 16:58

	Type	L #	Hits	Search Text	DBs	Time Stamp
28	BRS	L28	25	((emitter) near16 (intrinsic near base) near15 (extrinsic)) same ((oxide) and (base near2 resistance))	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 16:58
29	BRS	L29	1	((emitter) near16 (intrinsic near base) near15 (extrinsic)) same ((oxide) and (base near2 resistance)) same (current)	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 17:00
30	BRS	L30	0	((emitter) near16 (intrinsic near base) near15 (extrinsic)) same ((oxide) and (base near2 resistance)) same (travers\$3 near15 current)	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 17:00

	Type	L #	Hits	Search Text	DBs	Time Stamp
31	BRS	L31	0	((emitter) near16 (intrinsic near base) near15 (extrinsic)) same ((width near5 oxide) and (base near2 resistance)) same (current)	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 17:01
32	BRS	L32	0	((emitter) near16 (intrinsic) near15 (extrinsic)) same ((width near5 oxide) and (base near2 resistance)) same (current)	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 17:01
33	BRS	L33	0	((emitter) near15 (extrinsic)) same ((width near5 oxide) and (base near2 resistance)) same (current)	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 17:01

	Type	L #	Hits	Search Text	DBs	Time Stamp
34	BRS	L34	2	((emitter)) same ((width near5 oxide) and (base near2 resistance)) same (current)	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 17:04
35	BRS	L35	29	((emitter)) near35 ((width near5 oxide) and (base near2 resistance))	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2004/11/0 3 17:04